This Page Is Inserted by IFW Operations and is not a part of the Official Record

BEST AVAILABLE IMAGES

Defective images within this document are accurate representations of the original documents submitted by the applicant.

Defects in the images may include (but are not limited to):

- BLACK BORDERS
- · TEXT CUT OFF AT TOP, BOTTOM OR SIDES
- FADED TEXT
- ILLEGIBLE TEXT
- SKEWED/SLANTED IMAGES
- COLORED PHOTOS
- BLACK OR VERY BLACK AND WHITE DARK PHOTOS
- GRAY SCALE DOCUMENTS

IMAGES ARE BEST AVAILABLE COPY.

As rescanning documents will not correct images, please do not report the images to the Image Problem Mailbox.

(12)

EUROPEAN PATENT APPLICATION

(43) Date of publication:

11.07.2001 Bulletin 2001/28

(21) Application number: 00127786.2

(22) Date of filing: 19.12.2000

(51) Int CL7: G02B 13/18, G02B 13/14, G03F 7/20

D*15055EP*

(84) Designated Contracting States: AT BE CH CY DE DK ES FI FR GB GR IE IT LI LU MC NL PT SE TR Designated Extension States: AL IT IV MK ROSI

Europäisches Patentamt European Patent Office

Office européen des brevets

(30) Priority: 29.12.1999 US 173523 P

02.08.2000 US 222798 P (71) Applicants:

· Carl Zelss 89518 Heldenheim (Brenz) (DE) Designated Contracting States: BE CH DE DK ES FI FR GR IT LI LU MC NL PT SE

· Carl Zeiss Stiffung Trading as Carl Zeiss 89518 Heldenheim (DE) **Designated Contracting States:** GB IE

(72) inventors:

Shafer, David R.

Fairfield, Connecticut 06430 (US)

· Uirlch, Wilhelm 73434 Aalen (DE)

· Beierl, Helmut

89522 Heldenheim (DE)

(74) Representative: Dr. Weitzei & Partner Friedenstrasse 10 89522 Heidenheim (DE)

Projection exposure lens with aspheric elements (54)

The invention relates to a projection exposure (57)iens with

an object plane, optical elements for separating beams, a concave mirror.

an image plane.

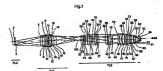
a first lens system arranged between the object plane and the optical elements for separating beams.

a second double passed lens system arranged between the optical elements for separating beams and the concave mirror, and

a third lens system arranged between the optical elements for separating beams and the image plane.

The invention is characterized in that

at least one of the lens or mirror surfaces of the first, second or third lens system is aspheric and the numerical aperture NA of the projection exposure lens is 0,7 or greater, preferably 0,8 or greater with a maximum image height exceeding 10mm.



Description

10

45

50

1. Fleid of the invention

[0001] The present invention relates to a projection exposure lens in a projection exposure apparatus such as a wafer scanner or a wafer stepper used to manufacture semiconductor elements or other microstructure devices by photolithography and, more particularly, to a catadioptric projection optical lens with an object side catadioptric system and a refractive system for use in such a projection exposure apparatus.

2. Related Background Art

[0002] US 4,779,966 to Friedman gives an early example of such a lens, however the catadioptric system being arranged on the image side. Its development starting from the principle of a Schupmann achromat is described. It is an issue of this patent to avoid a second lens material, consequently all lenses are of fused silica. Light source is not

specified, band width is limited to 1 nm. [0003] US 5,052,763 to Singh (EP 0 475 020) is another example. Here it is relevant that odd aberrations are substantially corrected separately by each subsystem, wherefore it is preferred that the catadioptric system is a 1:1 system and no lens is arranged between the object and the first deflecting mirror. All examples provide only fused silica lenses. NA is extended to 0.7 and a 248 nm excimer laser or others are proposed. Line narrowing of the laser is proposed as

sufficient to avoid chromatic correction by use of different lens materials. [0004] US 5,691,802 to Takahashi is another example, where a first optical element group having positive refracting power between the first deflecting mirror and the concave mirror is requested. This is to reduce the diameter of the mirror, and therefore this positive lens is located near the first deflecting mirror. All examples show a great number of

[0005] EP 0 736 789 A to Takahashi is an example, where it is requested that between the first deflecting mirror and the concave mirror three lens groups are arranged, with plus minus plus refractive power, also with the aim of reducing the diameter of the concave mirror. Therefore, the first positive lens is located rather near to the first reflecting mirror.

Also many CaF2 lenses are used for achromatization. [0006] DE 197 26 058 A to Omura describes a system where the catadioptric system has a reduction ratio of 0.75 $\leq \beta_1 \leq 0.95$ and a certain relation for the geometry of this system is fulfilled as well. Also many CaF₂ lenses are used

[0007] For purely refractive lenses of microlithography projection exposure system a lens design where the light beam is twice widened strongly is well known, see e.g. Glatzel, E., Zeiss-Information 26 (1981), No. 92, pages 8-13. A recent example of such a projection lens with + -+-+ lens groups is given in EP 0 770 895 to Matsuzawa and Suenaga. [0008] The refractive partial objectives of the known catadioptric lenses of the generic type of the invention, however,

show much simpler constructions. [0009] A catadioptric projection exposure lens comprising lenses or mirrors which are aspheric are known from JP 10-10429 and EP 0 869 383.

[0010] According to JP 10-10429 the aspheric surface is placed in the vicinity of a reflecting mirror.

[0011] By placing the aspheric surface in vicinity of the reflecting mirror, a good correction of distortions is achieved. Furthermore the system according to JP 10-10429 comprises an intermediate image.

[0012] From EP 0 869 383 a catadloptric system comprising at least two aspheric surfaces is known. For correcting off-axis-aberration one of the aspheric surfaces satisfies the condition

and for correcting on-axis-aberration the other of the aspheric surfaces satisfies the condition

0.85 < h/b < 1.2. . ~

whereby h is the height at each lens surface of the light beam that is assumed to be emitted from the intersection of the optical axis and the object plane and passes through the lens surfaces with the maximum numerical aperture NA and \$ is the radius of the diaphragm of the aperture stop. Subject matter of EP 0 869 383 therefore is to ensure a high

Image quality by using aspheric surfaces. [0013] Only as a point amongst others EP 0 869 383 mentions that by using asphenic surfaces the number of lenses In a catadioptric system can be decreased. Furthermore EP 0 869 383 relates only to systems with an intermediate

image. As special embodiments EP 0 869 383 shows systems with the first aspheric surface placed near the intermediate Image while the second aspheric surface is placed near the concave mirror of the catadioptric system or near the aperture stop.

10014] WO 99/52004 shows embodiments of catadioptric objectives with few lenses, some of them being aspheric. From WO 99/52004 a system with 16 lenses, at least four of them being asphenc lenses and a numerical aperture of

0.65 is known. [0015] From E. Heynacher, Zeiss-Information 24, pp. 19- 25 (1978/79), Heft 88, it is known that with complicated optical systems it is less appropriate to treat imaging errors separately by aspheres, but to influence the correction of the imaging errors as a whole.

3. Summary of the invention

10

15

20

25

30

[0016] It is an object of the present invention to obtain a catadioptric optical system of new construction principles allowing for large numerical aperture, large image field, sufficient laser bandwidth, solid and stable constructions, which takes into account the present limitations on availability of CaF2 in quantity and quality. Therefore it is the major object of the present invention to minimize the number of lenses in a projection exposure lens for DUV (193 nm) and VUV (157 nm) systems. Furthermore said systems should not be restricted to systems with an Intermediate image.

[0017] In order to achieve the above object, according to the present invention, there is provided a projection exposure lens according to claim 1.

[0018] It is a further object of the invention by minimizing the number of lenses to reduce the absorption and the reflection losses of the whole projection exposure lens.

[0019] Said further object is achieved by reducing the number of lenses in the second double passed lens system of the projection exposure lens since in the double passed lens system undesirable effects of absorption in the lens material and of reflection losses at the surface count twice.

[0020] According to the invention the second lens system comprises at maximum five lenses, preferably two or three lenses.

[0021] In a preferred embodiment of the Invention negative refraction power is arranged in the second lens system between the optical elements for splitting beam and the concave mirror. Said negative refraction power is split into advantageously two negative lenses.

[0022] In a further preferred embodiment for correcting the chromatic length aberration CHL the second lens system provides for a over correction while the first and third lens system provides for a under correction.

[0023] The long drift section in the second lens system according to the invention provides for several advantages:

- Mounting of the lens components in the second lens system is less complicated than in objectives known from the prior art.
- The lenses of the second lens system and the concave mirror could be mounted as a separate lens group, no metallic tube is necessary between the optical elements for splitting beam and the first lens of the second lens system.

[0024] Further advantageous embodiments are obtained when including features of one or more of the dependent

[0025] An advantageous projection exposure apparatus of claim 62 is obtained by incorporating a projection exposure lens according to at least one of claims 1 to 61 into a known apparatus.

[0026] A method of producing microstructured devices by lithography according to the invention is characterized by the use of a projection exposure apparatus according to the preceding claim 62. Claim 63 gives an advantageous mode of this method.

[0027] The present invention will be more fully understood from the detailed description given hereinbelow and the accompanying drawings, which are given by way of illustration only and are not to be considered as ilmiting the present invention. Further scope of applicability of the present invention will become apparent from the detailed description given hereinafter. However, it should be understood that the detailed description and specific examples, while indicating preferred embodiments of the Invention, are given by way of illustration only, since various changes and modifications within the spirit and scope of the invention will be apparent to those skilled in the art from this detailed description.

Brief Description of the Drawings

rn	n	2	R

35

	-	
5	Figure 1	is a section view of the lens arrangement of a first embodiment;
	Figure 2	is a section view of the lens arrangement of a second embodiment;
	Figure 3	is a section view of the lens arrangement of a third embodiment;
10	Figure 4	is a section view of the lens arrangement of a fourth embodiment;
	Figure 5	is a section view of the lens arrangement of a fifth embodiment;
15	Figure 6	is a section view of the lens arrangement of the sixth embodiment; and
	Figure 7	is a section view of the lens arrangement of the seventh embodiment;
	Figure 8	is a section view of the lens arrangement of a eighth embodiment;
20	Figure 9	is a section view of the lens arrangement of a ninth embodiment;
	Figure 10	is a section view of the lens arrangement of a tenth embodiment;
25	Figure 11	is a view of an alternative arrangement of the folding mirrors.

[0029] First a projection exposure apparatus in which an projection exposure lens according to the invention could be used is described without showing a figure thereof. A projection exposure apparatus includes for example an excimer laser light source with an arrangement moderately narrowing bandwidth. An illumination system produces a large field, sharply limited and illuminated very homogeneously, which matches the telecentricity requirements of the projection lens, and with an illumination mode to choice. Such mode may be conventional illumination of variable degree of coherence, annular or quadrupole lliumination.

[0030] A mask or a reticle is displaced in the illuminated area by a mask resp. reticle holding and handling system which includes the scanning drive in case of a wafer scanner projection exposure apparatus. Subsequently follows the projection exposure lens according to the invention to be described in detail subsequently.

100311 The projection exposure lens produces a reduced scale image of the mask on a wafer. The wafer is held, handled and eventually scanned by a scanning unit. [0032] All systems are controlled by control unit. Such unit and the method of its use is known in the art of micro-

lithographic projection exposure.

100331 However, for exposure of structures in the regime of about 0.2 μm and less resolution at high throughput there is a demand for various projection exposure lenses capable to be operated at 193 nm, eventually also at 248 nm or 157 nm excimer laser wavelengths with reasonably available bandwidths (e.g. 15 pm at 193 nm), at high image side numerical aperture of 0.65 to 0.8 or more and with reasonably large rectangular or circular scanning image fields of e. g. 7 x 20 to 10 x 30 mm².

[0034] This design concept can be easily modified for 126 nm wavelength with appropriate lens material, e.g. LiF. [0035] Systems according to the state of the art cited above are in principle suitable for this.

[0036] However, according to the invention a number of measures and features has been found to improve these

[0037] The example shown in the sectional view of figure 1 has the lens data given in Table 1 in code-V-format in the annex and makes use only of fused silica lenses. As only one lens material is used, this design can easily be adapted for other wavelengths as 248 nm or 157 nm. The numbers for the objects in table 1 are identical to the reference

[0038] The intermediate image IMI is freely accessible, so that it is easily possible to insert a field stop. The aperture

stop STO is also well accessible. [0039] The splitting of the beam in the catadioptric system is not shown in the embodiments depicted in figures 1 -7. Beam splitting can be achieved e.g. by a physical beam splitter, e.g. a beam splitter prism as disclosed in US 5,742,436. The content of this document is enclosed fully herewith.

[0040] An alternative is the usage of deflecting mirrors. In such an embodiment the deflecting mirrors in the catadi-

optric system are defined in their geometry by the demands of separation of the light beams to and from the concave mirror 12 and of clearance from the lenses.

[0041] The arrangement of two deflection mirrors allows for a straight optical axis and parallel situation of origin plane 0 and image plane IMG, i.e. mask resp. reticle and wafer are parallel and can easily be scanned. However, one of the deflecting mirrors can be abandoned or eventually be replaced by a deflecting mirror in the third lens system TLS which is a refractive iens. It is also clear that the deflecting mirrors can be replaced by other deflecting optical elements, e.

g. prisms.

[0042] A moderate positive lens comprising surfaces 2, 3 is placed near the origin plane 1 in the first lens system FLS, which is a single beam area. Its focal length is approximately equal to its distance from the concave mirror 13. [0043] This makes that the concave mirror 13 is situated in a pupil plane and thus the diameter required is minimized. [0044] A further positive lens is located as a first lens with surfaces 6, 7 in the second doubly passed lens system SLS consisting of three lenses with surfaces 6, 7, 8, 9, 10, 11. As the production conditions of concave mirrors of 200 mm to 300 mm diameter give no strong preference to smaller units - in contrast to lenses, namely such made from

CaF2, where inhomogeneties etc. give strong limitations - there is no need to use this positive lens with surfaces 6, 7 for reduction of the radius of the concave mirror 100.

[0045] The two negative lenses with surfaces 8, 9, 10, 11 of the second lens system SLS cooperate with the concave mirror 13 in a known manner, giving increased angles of incidence and stronger curvature, thus stronger correcting Influence of the concave mirror 13.

[0046] It is significant, that the number of lenses in the doubly passed area of the catadioptric system is restricted to a low number, e.g. three as in this embodiment, since in this part of the optical system every lens counts double with respect to system energy transmission and wavefront quality degradation - without giving more degrees of freedom for correction.

[0047] The embodiment according to figure 1 comprises only one aspheric surface 9, 16 in the double passed second lens system SLS of the projection exposure lens. The aspheric surface 9, 16 is situated on the wafer or image IM-side

of the iens comprising said surface.

[0048] At the intermediate image plane IMI preferably a field stop is inserted, which reduces stray light favourably. [0049] The third lens system TLS following the intermediate image IMI is in principle known from the art. In the embodiment shown the third lens system does not comprise any aspheric surface. The details of the design are given in table 1 in code V-format in the annex of the application.

[0050] The example of the Invention according to figure 1 with an image side NA = 0.70 is suitable for printing microstructures at a resolution of less than 0.2 μm over an image field of 30 x 7 mm² rectangle at 6 mm off axis, with an excimer laser source of 0.015 nm bandwidth.

[0051] Figure 2 and table 2 show a design variant. The second lens system SLS comprises in total four lenses with surfaces which are passed twice. In contrast to the embodiment according to figure 1 the aspheric surface 160 is situated in the third lens system TLS facing towards the image IMG resp. the wafer. The details of this embodiment are given in table 2 in code-V-format in the annex. The numbers for the objects in table 2 are identical to the reference slans in figure 2.

[0052] Figures 3 and 4 and tables 3 and 4 in the annex show other examples of a projection exposure lens according to the invention. As in the antecedent example, all have an image side NA = 0.70. Furthermore the number of the objects in table 3 and 4 correspond to the reference numbers in the figures 3 and 4.

[0053] Now, the catadioptric system comprising the second lens system and the concave mirror shows a major revision, since the aspheric surface is situated on the concave mirror 211. This allows for reducing the number of lenses in the catadioptric system to a total number of three. Only the two negative lenses with surfaces 206, 207, 208, 209 have to be passed twice.

[0054] in the embodiment according to figure 3 the projection exposure lens comprises only one aspheric surface. whereas in the embodiment according to figure 4 a further aspheric surface is situated in the third lens system TLS. The further asphenic surface in the third lens system faces towards the image IMG resp. the wafer. The details of these embodiments are given in Tables 3 and 4 in code-V-format in the annex.

[0055] A fifth embodiment is given in figure 5 and table 5.

[0056] Now, aspheric surfaces are situated only in the third lens system.

[0057] Details of the system are given in Table 5 in code-V-format in the annex. The number of the objects in table

5 correspond to the reference number in figure 5. [0058] In the sixth embodiment of the invention shown in figure 6 the aspheric surfaces are situated in the third lens system on surface 533, 539 far away from the intermediate image IMI and in the second lens system SLS. In this

embodiment the concave mirror 513 of the second lens system comprises an asphenc surface. [0059] Details of the system are given in Table 6 in code-V-format in the annex. The number of the object in table 6

correspond to the reference number in figure 6. [0060] In the seventh embodiment of the invention shown in figure 7 the asphenic surfaces are situated in the third

lens system TLS on surface 631, 637, 648 far away from the intermediate image IMI as in embodiment 6 and in the first lens system on surface 603. In contrast to embodiment 6 the aspheric surface of the first lens system is situated on a lens near the object 0 resp. reticle instead on the concave mirror.

[0061] Details are given in table 7 in code-V-format in the annex. The number of the object in table 7 corresponds

to the reference number in figure 7.

[0062] WO 99/52004 cited in the inductory part of this application shows that with a generic catadioptric objective image side numerical apertures of up to 0.65 can be obtained with less than 15 lenses when entering at least 4 asperical lenses.

[0063] The Invention shows that increased resolution capabilities with numerical apertures of 0.7 to 0.85 and more, [0063] The Invention shows that increased resolution capabilities with numerical apertures of 0.7 No A range, at unrestricted image fields and with state of the art correction, are obtained with lesser aspheres in the 0.7 No A range. With the number of 16 lenses and one aspherical surface per lens and on the concave mirror even 0.85 NA is demonstrated as compared to 0.65 NA with 8 aspherical surfaces of 10 lenses and one planar plate of example 4 of the cited WO 99/52004-application.

cited wto 359 32000-approximation.

[D084] Its advantageous that between the object plane and the doubly passed group of lenses as a first lens system at least one lens is inserted, preferably exactly one. This could be a positive lens, it optimizes object side telecentricity. Aspherization of this lens, bending it to a meniscus, and aspherizing the concave surface are particularly preferred measures. Preferably, too, its object side surface has the smaller radius of curvature.

measures. Preterably, too, its object site surface has the sitement feature of the preterable to the first lens system FLS is also predestined to be used for implementation of correcting surfaces, which may be free-form aspheric surfaces, as it is easily accessible also after complete assembly of the lens.

which may be free-form aspheric surfaces, as it is easily accessible as an accession to each of the surfaces, as it is easily accessible as a left configuration of the surfaces, as it is easily accessible as a left configuration of the surfaces as a few months of the surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as it is a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces as a few months are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces are surfaces and surfaces are surfaces as a few months are surfaces. The surfaces are surfaces and surfaces are surfaces as a few months are surfaces as a few months are surfaces. The surfaces are surfaces are surfaces and surfaces are surfaces as a few months are surfaces. The surfaces are surfaces are surfaces as a few months aread and surfaces are surfaces as a few months are surfaces. The s

25

35

diameter of this system and consequently great cost reduction. [0667] Also the optical axis in the region of this first lens system can be shifted with respect to the parallel optical axis of the refractive partial system, away from the concave mirror. This allows for a better division of the illuminated areas on the two folding mirrors arranged nearby in the preferred variations of the invention. This offset is 2.95 mm in the examples of Fig. 5, 6 and 7 and is 17.5 mm in the NA = 0.75 are given in table 8 and 12.5 mm in the NA = 0.75 example of Fig. 9. The details of the embodiments of Fig. 8 and Fig. 9 are given in table 8 and table 9 in code-V-format in the annex. The number of the object in tables 8 and 9 correspond to the reference number in figures 8 and 9.

[0068] A tenth embodiment is shown in figure 10. The details of the tenth embodiment are given in table 10 in code—V-format in the annex. The number of the object in table 10 corresponds to the reference number in figure 10. The V-format in the annex. The number of the object in table 10 corresponds to the reference number in figure 10. The tenth of the control of 10.2. The image side aperture is NA = 0.80, tenth embodiment is a 5x reduction system with a magnification ratio of -0.2. The image side aperture is NA = 0.80, tenth embodiment is 10.00 for 10.00 for

are more distant from the object plane O than the first lens of the first lens group from the object plane Is.

[0069] Fig. 11 shows an alternative arrangement of the folding mirrors M1 and M2*, where they do not share a common ridge. Here even stronger axis shift is needed. The construction length between object and image can be reduced in this way, and new compromise possibilities in passing by of the light beams at the folding mirrors are opened.

[0070] The folding mirrors of the other shown examples are conveniently established on a common prism substrate.

[0071] Alternatively, the folding mirrors can be internal surfaces of prisms passed by the light beam. The higher refractive index of prism material: I.e. calcium fluoride, other crystals, quartz glass or other optical glass - then allows

for more compact transfer of high aperture beams.

[0072] Advantageously they are coated with reflection enhancing thin films, which can even more advantageously correct variations in phase shifts caused by reflections under different angles by adapted thicknesses.

correct variations in phase shirts caused by reuseance under under the angular phase shirts caused by reuseance under under the folding mirrors can be formed with slight aspherior non-rotationally symmetric, free-form surface forms for correction of these phase effects as well as other thy errors of imaging of the system or of production toler-forms for correction of these phase effects as well as other thy errors of imaging of the system or of production toler-

arruses.
[0074] The preferred configuration of the invention differs from the cited art in that the double pass lens second lens [0074] system and concave mirror are arranged along an unfolded optical axis, with two folding mirrors in the region, where system and concave mirror are arranged along an unfolded optical axis, with two folding mirrors in the region, where

the optical axis of this subsystem crosses with those of the first lens group and the refractive partial objective. The folding angle between the optical axis of the double pass second lens system and the other axes advantageously deviates from 90° such that at the lenses and the mirror all light beams are more distant from the object plane than the first lens surface of the first lens group is. Consequently, the necessary free access to the object plane needed for scanning does not interfere with the space needed for the mounts of the optical elements.

[0075] A further issue of the invention lies in the design of the double pass lens group having a minimal number of lenses. Each degree of freedom for correction of the imaging obtained by an additional lens here has twice the undestrable effects of absorption in the lens material and of reflection losses at the surfaces. Consequently only the lenses needed for putting into effect the concave mirror, for separating the light bundles at the folding mirrors and for keeping the length of the side arm established by the double pass group relatively short are provided.

(0076) In the examples shown the intermediate image IMI directly follows after the folding mirror arranged subsequent to the double path lens group. Though the space between this folding mirror and the intermediate image tends to be narrow, one or other lens can well be introduced here.

10

50

[0077] The lenses arranged after and near the intermediate image IMI are Illuminated by light bundles situated strongly off axis, so that lens heating caused by light absorption leads to strongly asymmetric disturbing effects. Consequently, the number of lenses in this space is kept low, with normal forms and thicknesses to keep these lens heating influences

[0078] Aspherization of the lens next to the intermediate image is strongly suggested by EP 0 869 383. However, besides the above named asymmetry effect, there are further aspects making this less preferable. Once, the intermediate image is per its function in the objective badly corrected, so that the named separation of field specific image errors is disrupted.

[0079] Then, e.g. from E. Heynacher, Zeiss-Inform. 24, 19-25 (1978/79) Heft 88, it is long known that with complicated optical systems it is less appropriate to treat the imaging errors separately by aspheres, but to influence the correction of all imaging errors as a whole. Consequently it is preferred to distribute the aspheres onto lens surfaces of different relative influences to the relevant imaging errors.

[0080] Especially, the effect of aspherization of the first lens at the object side shows stronger influence onto distortion than a lens very near to the intermediate image can have.

[0081] EP 0 869 383 gives another condition for aspherical surfaces, namely 0.85 < h/\$\phi\$ < 1.2, which is of less relevance, as shown by the example of Fig. 9 and table 9. Here this parameter is for the aspheric surfaces 803 = 0.09, 811 = 1.22, 813 = 1.23, 834 = 0.84, 844 = 0.70, 849 = 0.14. Consequently, it is advantageous for the correction of high NA objectives of this sort, if one or more aspheric surfaces features this parameter high > 1.2.

NA objectives to this sort, if offer in more aspherical surfaces situated oppositely, separated by a narrow air space, is introduced at the aspherical concave mirror 813 and the opposing surface 811 of the neighboring negative meniscus. This is contrary to the concept of one asphere per error to be corrected and allows for more precise influencing of the correction state of an objective - also in other optical concepts.

[0083] In the refractive partial objective a long drift space intermediate the intermediate image IMI and the aperture stop STO is typical, while the space between aperture stop STO and image plane IMG is densely packed with lenses. A meniscus concave versus the aperture stop STO, establishing a positive air lens with the nelighboring lens is a typical correcting element introduced in previous applications of the inventors. This concave surface (844 in Fig. 9) is also a very effective location of an aspheric surface. Preferably this or other asphere In the space between aperture stop STO and image plane IMG is paired by an asphere (834 in Fig. 9) arranged approximately symmetrically on the other side

of the aperture stop STO.

[10084] In the high numerical aperture applications of the invention also the most image-sideward lens is advantageously aspherized, namely on its image side, as surface 849 in Fig. 9 and as surface 749 in Fig. 8. Here the greatest incidence angles of the light rays occur and give special influence of the aspherics here.

[0085] Ongoing acceleration of the semiconductor roadmap forces the industry to extend optical lithography much further than ever expected. Including 157 nm wavelength radiation, today it is believed that optical lithography could even enable manufacturing at the 70 nm node of resolution under commercial conditions. The 50 nm node would require at least 157 nm optics with extremely high numerical apertures (>0.8). Extending wavelength further down to 128 nm (Arz-laser), would only help if optics (mirrors and a few transmittive, refractive lens elements, preferably Life lines elements) can achieve numerical apertures well above 0.7. Translating the semiconductor roadmap into an exposure tool roadmap, not only new wavelengths are needed, but also extremely high NA optics will be introduced. To assure high enough process latitude, resolution enhancement methods will be implemented in volume manufacturing. Next to advanced mask technology, layer-tailored litumination schemes will be used.

[0086] As such illumination with linearly polarized light and with a quarter-wave plate at the aperture stop plane for image-side circularly polarized light is advantageous. An alternative can be radially polarized light as described in DE 195 35 392 A (US ser. No. 08/717902) of the same assignee.

[0087] Such high numerical aperture objectives are provided by the invention, with Fig. 8 and table 8 giving the

extreme image side numerical aperture NA = 0.85 at 6x reduction, with a 22 mm x 7 mm slit scanning image fleid, ± 0.6 pm laser bandwidth at the 157.1 nm excimer laser line, with all lenses made from calclum fluoride crystal. Naturally, at this elevated demand for correction, the limit of 15 lenses given in WO 99/52004 with examples of moderate NA = 0.65, is excee ded - but only by one additional lens, at 9 aspherical surfaces. Polychromatic wavefront aberration shows a maximum of 20 milliwaves at all field heights - a reasonably good imaging quality at these conditions.

[0088] The embodiment of Fig. 9 and table 9 features at 5x reduction imaging with a 22 mm x 7 mm image field at 157.1 nm \pm 0.6 pm with the high image side NA = 0.75. The 16 lenses and 1 concave mirror obtain this at a wavefront error of maximal rms of 21 milliwaves with only 5 aspherical surfaces as described above.

[0089] If preferred for reasons of gas purging at the reticle or wafer, the object side as well as the image side of such objectives can be a planar surface, either by introducing a planar protecting plate as is in widespread use, e.g. in WO 99/5/2004, or by changing design under the restriction of a planar face.

10

20

25

30

99/22/us, or oy changing design under the restriction of a planta reco.

[0090] The invention covers all the combinations and subcombinations of the features give in this specification and the claims, drawings and tables.

[0091] While examples are given for the scanning scheme of exposure, the invention as well is useful with step-andrepeat or stitching. Stitching allows for specifically smaller optics.

Annex: Code-V-tables of the objectives shown in fig. 1-10

table 1: wavelength = 193,31 nm

	Object Radiu	s Thickness RMD	Glass sort	
	•			
		:··		
	> OBJ: INFINITY	0.000000		
	1: INFINITY	35.000000		
	2: 534.41573	16.000000 .	'SIO2HL'	
	3: -2605.52657	82.00000		
	4: INFINITY	423.377560		
	5: INFINITY	0.000000		
	6: 524.08780	50.000000	'SIO2HL'	
	7; 903.54667	44.861212		
1	8: -263.10576	15.000000	'S102HL'	
	9; -1376.18978	33.775444		
	ASP:	•		
	к : 0.000000			
	IC: YES	CUF: 0.000000		D :0.000000E+00
	A :0.983295E-10	B :0.156925E-14	C :0.660351E-20	D :0.000000E+00
5			'SIO2HL'	
	10: ~209.43665	15.000000	SIOZHL	1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 - 1 -
	11: -400.74819	12.442047		
	12: INFINITY	0.000010 RE		
	13: 278.05481	12.442047 RE	'SIO2HL'	
	14: 400.74819	15.00000	310201	
U	15: 209.43665	33.775444-	'SIO2HL'	- 7
	16: 1376.18978	15.000000	STOZAL	
	ASP:			
	к : 0.000000			
	IC : YES	CUF: 0.000000	C :660351E-20	D :0.000000E+00
5	A :983295E-10	B :156925E-14	C :660351E-20	D
	17: 263.10576	44.861212		
	18: -903.64667	:50.000000	'SIO2HL'	
	19:524.08780	449.719482		
	20: INFINITY	0.00000	•	
	21: INFINIT			
10	22: 367.04203	39.381898	'SIO2HL'	
	23: -813.9353	12.355245		
	24: 862.20789	26.902539	'SIO2RL'	
	25: -2189.1159	19.271290		
	26: -280.3291	6 23.514083	'SIO2HL'	
45	27: 551.0135	2 7.025237		
	20. 1073.2382		'SIO2HL'	

Annex: Code-V-tables of the objectives shown in fig. 1-10

table 1: wavelength = 193,31 nm

10	Object	Radius	Thickness RMD	Glass sort
			•	
15	29:	393.66672	1.000000	
15	30:	942.86330	31.837703 '	'SIO2HL'
	31:	-734.28385	17.595477	
	32:	471.84849	34.925052	'SIO2IIL'
	33:	223.32640	54.276947	
	34:	-238.14826	16.480387	, SIOSHT,
20	35:	-432.42551	1.000000	
	36:	846.35305	38.186692	'SIO2IIL'
	37:	-382.59164	135.289717	
	38:	431.86893	43.207971	'SIO2HL'
	39:	14250.66524	1.000000	
25	40:	290.44991	15.459700	'SIO2HL'
25	41:	183.43506	56,245505	
	42:	~238.71906	28.322086	'SIO2HL'
	43:	-689.33370	114.792439	
	44:	-429.48801	28.350285 .	'SIO2HL'
	45:	-258.98856	1.000000	
30	46:	398.85931	39.841410	'SIO2HL'
	47:	230.04262	11.000000	'STO2HL'
	48:	324.81640	49.875208	SIOZRI
	49:	-854.01841	1.000000	'SIQ2IIL'
	50:	221.87147	18.942210	5102111
35	51:	167.65528	16.891234	'SIO2HL'
55	52:	253.72485	28.225022	STOZAL
	53:	7134.26986	0.790361	
	STO:	INFINITY	5.370968	'SIO2HL'
	55:	156.41574	37.458696	STOTE
	56:	425.02539	13.790057	'SIO2HL'
40	57:	2532.66232	21.354413	3102110
	58:	-487.11572	0.100000	'S102HL'
	59:	-754.17801	35.849436	5102
	60:	117.83998	10.996190	'SIO2HL'
	61:	174.62750	35.656142	Broam
45	62:	-1054.34644	0.100000	'CAF2HL'
	63:	110.05260	64.820400	Ç, 200
	64:	4815.31686	0.100000	'CAF2HL'
-	65:	241.11586	26.846900 14.164338	سبية عبت
	66:	-465.81838	-0.000247	
	IMG:	INFINITY	-0.000247	

table 2: wavelength = 193,31 nm

Object	Radius	Thickness RMD	Glass sort	
,			5	
				-
		-		
		v 0.000000		
> OBJ:	INFINIT	•		
101:	INFINIT:			'SIO2HL'
A02:	-18962.2341			
٠ <u>٠</u> ٥3:	INFINIT			
104:	INFINIT			
405:	513.1083			'SIO2HL'
106:	-789.1984			
101:	-431.0844			'SIO2HL'
408:	2470.3924			
109:	-305.2201			'SIO2HL'
110:	-2422.5720			
A11:	-202.2421			'SIO2HL'
A12:	-372.8997			
∤ 13:	INFINIT		REFL	
A14:	277.5861		REFL	
<i>አ</i> 15: ፈ 16:	372.8997			'SIO2HL'
	202.2421			
417: 418:	2422.5720			'SIO2HL'
A19:	305.2201			
A20:	-2470.3924			'SIO2HL'
, 20. , 21:	431.0844			
122:	789.1984			'SIOZHL'
À23:	-513.1083			
A24:	INFINI			
A25:	INFINI			
A26:	390.527	26 31.324696		'SIO2HL'
127:	-683.314	37 6.752019		
A28:	1069.128	04 24.466364		'SIO2HL'
129:	-1717.095	22 19.648878	l	
.,				

table 2: wavelength = 193,31 nm

5	Object	t Radius	Thickness RMD	Glass	sort	
			*.		'SIO2HL'	
	J 30:	-271.40065	24.662421		, 2107HP	
10	A31:	585.28487	4.258045		'SIO2HL'	
	432:	1037.54513	47.522078		3102111	
	433:	-299.20504	1.000000		'SIO2HL'	
	434:	1517.35976	14.493847			
	435:	-1667.38733	29.793625 38.496191		'SIO2HL'	1.
15	436:	. 374.98529 215.15028	58.456542			
	1 37:	215.15048	38.030342			
	A38:	-244.39173	20.364718		'SIO2HL'	
	A39:	-481.59968	1.000000			
	A40:	685.96658	50.000000		'SIOZHL'	
	A41:	-466.91597	124.805511			
20	A42:	337.88037	26.730825		'SIO2HL'	••
	43:	60685,02516	1.000000			
	144:	307.00084	25.717686		'SIO2HL'	
	445:	173,62675	54.501370			
	146:	-283.94563	28.052025		'SIO3HL'	
25	147:	-1327.60130	127.853517			
	448:	-457.68711	32.289214		'SIO2HL'	
	149:	-280.72637	1.000000.		'SIO2HL'	
	450:	350.95083	33.551443		3102110	
	451:	233.87449	11.000000		'SIO2HL'	
30	λ 52:	316.35603	44.382117 1.000000			-
30	A53:	-1117.42550 218.72076	22.816384		'SIO2HL'	
	ハ 54: 시 55:	170.60059	13.066780			
	A 56:	248.49595	27,215517		'SIO2HL'	
	A 57:	2867.70932	-0.636677			
	STO:	INFINITY	5.190673			
35	A 59:	159.10817	37.337945		'SIOZHL'	
	A 60:	450,28461	13.813926	-		
	ASI					
	ĸ	: 0.000000				
		: YES	CUF: 0.000000		.294548E-17	D :112803E-21
40	A	:0.284543E-09	B :121419E-12	G :0	.000000E+00	H :0.000000E+00
	E	:0.107208E-26	F :0.606134E-30	G		
	J	:0.000000E+00				
	1614	4993.99819	56,358019		'SIOZHL'	
	462:	125.35419	8.227596			
	A63:	178.76516	35.546249		'SIO2HL'	
45	A 64:	-544.56516	0.100000			
	A65:	111.13737	65.000000		'CAF2HL'	
	166:	633.24492	0.100000		'CAF2HL'	
	167:	218.73155	30.206802		CWLTH	
	168:	-335.35055	12.082469			
50	IMG:	INFINITY	0.000503			

table 3: wavelength = 193,31 nm

5

5	Object	Radius	Thickness RMD	Glass	s sort		
				•			
10			0.00000				
	> OBJ:	INFINITY	35.000000				
	201:	INFINITY	21.000000		'SIOZHL'		
	202:	412.00283	82.000000		2102		
	20 3:	13807.40229	473.169978				
	204:	INFINITY INFINITY	0.000000				
15	205:	-253.51555	16.000000		'SIO2HL'		
	206:	-544.16517	27.805541	•			
	207 : 208 :	-205.78974	16.000000		'SIO2HL'		
	209:	-424.01744	13.131367				
	210:	THEINITY	0.000010	REFL			
(20	211:	282.11038	13.131367	REFL			
, 20	ASE						
	ĸ	0.000000					
	ic	YES	CUF: 0.000000			_	:127469E-23
	A	:0,102286E-09	B :0.163583E-14		:0.222395E-19	D	:0.000000E+00
	E	:0.130171E-27	F :388631E-32	G	:0.000000E+00	н	:0.00000000+00
25	J	:0.000000E+00					
					'SIO2HL'		
	212.	424.01744	16.000000		SIUZHL		• •
	213:	205.78974	27.805541		'SIO2HL'		-
	214:	544.16517	16.000000		. STOZHU		
	Ž15:	253.51555	530.616842				
30	715:	INFINITY	0.000000				
	717:	INFINITY	63.778860		'SIO2HL'		
	218:	636.23394	27.336162		STORILL		
	Z 19:	-774.44237	0.100000				

table 3: wavelength = 193,31 nm

20

Object	Radius	Thickness RMD	Glass sort
	630 AF16E	27.867198.	'SIO2HL'
220:	638.45165 -950.10950	26.668510	
221:	-332.85587	38.386102	'SIO2HL'
Z 22:	866.08021	18.442845	
٠ كَ23 :	-1525.57443	47.039609	'SIO2HL'
224:	-390.53318	1.000000	
Z25 : Z26 :	1733.78965	28.403565	'SIO2HL'
227:	-524.35781	0.100000	
227: 228:	835.74339	16.000000	'SIO2HL'
2 20: 2 29:	298.64601	57.500000	
2 30:	-259.59279	16.000000	'SIO2HL'
Z31:	-411.70682	1.000000	
2 32:	1128.90538	36.253267	'SIO2HL'
2 :33:	-477.96774	253.556594	
234:	435.03169	32.866003	'SIO2HL'
235:	-2559.42430	1.000000	
236:	275.15076	16.000000	'SIO2HL'
237:	187.82645	.66.000000	
238:	-296.62496	44.201058	'SIO2HL'
239:	-690.62720	135.986515	
240:	4019.70777	21.709054	'SIO2HL'
241:	-800.90710	1.000000	
2 42 :	853.98857	50.00000	'SIO2HL'
-243:	254.20904	12.399910	10700117 1
244:	408.20829	38.016254	'SIO2HL'
. 245∶	-643.03332	1.000000	'SIO2HL'
₹46:	228.71372	16.000000	SIOZRE
247:	175.28033	14.986197	'SIO2HL'
248:	269.82502	31.500000	SIUZHU
2.49:	20733.22818	-7.061102 8.061102	
STO:	INFINITY	37.926522	" 'SIO2HL'
2.51:	160.50399	12.706908	5103135
2.52:	457.13661 1597.64988	23.273549	'SIO2NL'
253:	-728.49646	0.100000	
254 : 255 :	-2709.38689	37.761809	'SIO2HL'
2.56 :	120.00817	10.277526	
256 : 257 :	171.38842	38.220630	'SIO2HL'
2 57:	-2029.55473	0.100000	
2 59 :	116.83775	64.846281	'CAF2HL'
2 60 :	1815.17026	0.100000	
261:	212.15910	28.928425	'CAF2HL'
5 62:	-501.97805	15.000534	•
TMG:	INFINITY	-0.000523	

table 4: wavelength = 193,31 nm

45

	Object	Radius	Thickness RMD	Glass sort	
			. *		
			•		
0			•	•	
	> OBJ:	INFINITY	0.000000	U . *	
	301:	INFINITY	35.000000		
5	30 2	434.57513	22.000000	'SIO2HL'	
,		36267.41000	82.000000		
	304	INFINITY	477.044163	and the second second	
	305:	INFINITY	0.000000		
	306:	-254.30195	16.000000	'SIO2HL'	
	307:	-532.25303	29.144125		
20	308:	-204.79768	16.000000	'SIO2HL'	
	30.9:	-421,29373	13.323325		
	310	INFINITY	0.000010	REFL	
	311:	285.25831	13.323325	REFL	
	ASP:				
	К :	0.000000	•		
25	IC:	YES	CUF: 0.000000		D :466752E-24
	A :	.116419E-09	B :0.112957E-14	C :937828E-20	H :0.000000E+00
	E : (.506427E-28	F :185566E-32	G :0.000000E+00	H .0.000002.00
	J: E	0.000000E+00	*		
				'STO2HL'	_
	312:	421.29373	16.000000	· S102HL	
30	313:	204.79768	29.144125		
	314:	532.25303	16.000000	. 'SIO2HL'	
	3 15:	254.30195	537.666508		
	316:	INFINITY	0.000000		
	317:	INFINITY	63.778860	'SIO2HL'	
35	318:	801.47063	30.675310	. 510280	
55	3 19:	-741.91592	0.100000	'SIO2HL'	
	320:	852.20028	21,124661	5102Ab	
	3 21:	-1040.41670 -	31.707289	'SIO2HL'	
	322:	-270.54645	26.187590	210240	
	.323:	600.48250	18.319696		

table 4: wavelength = 193,31 nm

	Object	Radius	Thickness RMD GI	ass sort		
	4			-		
o			. · ·			
	324:	774.95053	41.436216.	'SIO2HL'		
	325:	-355.71105	1.000000			
	326:	1591.83158	29.490290	'STO2HL'	•	
	327:	-556.23481	53.458289			
	328:	854.87463	16.000000	'SIO2HL'		
5	329:	282.30181	54.422763 -			
	330:	-261.43332	24.488537	'SIO2HL'		
	331:	-411.65692	1.000000			
	332:	1107.48205	37.032421	'SIO2HL'		
	333:	-513.59706	246.562860			,
	334:	423.57328	28.982815	'SIO2HL'		ţ
20	335:	76613.31446	1.000000			
	336:	237.50869	16.000000	'SIO2HL'		
	337:	171.60021	63.162192			
	338:	-285.36403	50.00000	'SIO2HL'		
	.339 :	-902.91449	95.050310			
	340:	-733.54713	21.388284	'SIOSHL'		
25	341:	-375.20521	1.000000			
	342:	436.34842	50.000000	'SIO2HL'		
	343 :	264.04939	12.000000	'SIO2HL'		
	344:	395.02148	37.208539	SIUZRL		
	345:	-792.61152	1.000000	'SIO2HL'		
30	346:	215.61815	20.499145	SIGABL	•	
-	347:	165.98868	14.685149	'S102HL'	- 1	
	348:	248.36356	31.000000	SIGNED		
	349:	3136.09812	-8.174425		•	
	STO:	INFINITY	9.174425	'S102HL'	* *	
	351:	149.01853	41.331450 14.435195	3102115		
35	352:	363.61783	14.433133			
	ASI					
	K	: 0.000000	CUF: 0.000000			
	IC	: YES :0.106229E-08	B :233769E-12 C	:128409B-17	D :720355E-21	
	A	:0.577731E-25	F :147820E-29 G		H :0.000000E+00	
	E	:0.000000E+00	F 1470101 ,-			
40	J	:0.0000002+00				
	353:	881.72413	29.308297	'SIO2HL'		
	254:	121.03439	14.172084			
	355:	207.65180	41.413236	'SIO2HL'		
	356:	-639.91052	0.100000			
	357:	123.89834	65.000000	'CAF2HL'		
45	-358÷	609.59778	0.100000			
	359:	186.60911	35.732940.	'CAF2HL'		
	360:	-313.58998	15.000087			
	IMG:	INFINITY	-0.000089			
	IMG:					

table 5: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass sort	
			a .		
			•	· ·	
			0.00000		
10	> OBJ:	INFINITY	34.000000		
	401:	INFINITY	18.000000	'CAF2HL'	
	402:	326.89134	91.000000		
	ι ε <i>Ο</i> υ	7134.75200	438.917225		
	404 :	INFINITY	0.000000		
	405:	INFINITY	22.000000	'CAF2HL'	
15	406:	386.39605	23.000000		
	407:	3173.10800	13.000000	'CAF2HL'	
	408:	-263.73446	36.757293		
	409:	1274.99700	14.000000	'CAF2HL'	
	410:	-173.05552	12.325630		
	411:	-398.57456	0.000010	REFL	
0	412:	INFINITY	12,325630	REFL	
	413:	246.26462	14.000000	'CAF2HL'	
	414:	398.57456	36.757293		
	415:	173.05552	13.000000	'CAF2HL'	
	416:	-1274.99700	23.000000	4	
	417:	263.73446	22.000000	'CAF2HL'	
25	418:	-3173.10800	0.000000		
	٠19:	-386.39605	435.917225		
	420:	INFINITY	78.197752		
	421:	INFINITY	60.000000		-
	422:	INFINITY	-0.037541		
	423:	INFINITY	35.000000	'CAF2HL'	
30	424:	305.29233	33.00000		
	AS:			•	
	ĸ	: 0.000000	CUF: 0.00000	no	
	ıc	: YES	B :0.197982E-1	13 C :0.331141E-17 D	:546921E-21
	A	:983943E-08	F - 165982E-	29. G :0.000000E+00 H	:0.000000E+00
35	E	:0.476298E-25			
55	J	:0.0000002+00			
	1	-609.90977	175.000000		
	425:	-211.27437	20.000000	'CAF2HL'	
	426:	-211.27937	1.000000		
	427:	918.04784	32.000000	CAF2HL	
40	428:	-450.01625	10.220682		
	429:	211.00994	35.000041	'CAF2HL'	
	430:	147.86638	291.880529		
	431:	147.86656			

table 5: wavelength = 157,13 nm

. 5

. 5	Object	Radius	Thickness RMD	Glass sort	
	•	*			
					•
			2		
				. "	
10	ASP:				
	. к	. 0.000000	CUF: 0.000000		.158059E-22
	IC :	YES			.000000E+00
	A :0	.102239E-07		G :0.000000E+00 H :0	.0000002700
	E : 0	.105932E-24	P :746588E-30	•	
	J : 0	.000000E+00			
15			14.999813	'CAF2HL'	
	432:	302.52916	14.999813		
	433:	182.15262	32.488787	'CAF2HL'	
	434	325.54311	32.000000		
	435:	-472.69366	3.402424	'CAF2HL'	f -
	436:	132.72874	19.621815		- 1
20	437:	197.27963	19.825000	*	
	ASP:				
	· K	0.000000			
	ic:	YES	CUF: 0.000000	C :0.495156E-17 D :	0.179425E-21
	A :	0.132547E-07	B :0.196227E-12		0.00000E+00
		0.681679E-25	F :0.439118E-29	G :0.000000E+00 H .	
25	: 3	0.00000E+00			
		0.00000			
		INFINITY	30.976200	'CAF2HL'	
	STO:	1247.88900	2±.000000	CALLING	
	440:	-441.06952	1.000000	CAF2HL'	
		106.43847	30.279452	CAPAILL	
30	441:	390.31325	17.376730	'CAF2HL'	
	442:	-262.38753	10.000000	CAP AILL	
	443:	8245.04000	1.000000	'CAF2HL'	
	444:	105.22412	35.374148	, CAF ARL	
	445:	380.86930	1.000000	'CAF2HL'	•
	446:	131.60165	36.324916	- CAP AIN	
35	447:	-9747.89700	12.069889	•	
	448:				
	ASP				
	K		CUF: 0.000000	C :217607E-13 D	:0.684630E-16
		: YES :0.179402E-06	B :398734E-10	C :217007E 00 H	:0.000000E+00
40	A	:703555E-19		G :0.00000E+00 2	
40	E.	:0.00000E+00			
	J	:0.0000002700			
		INFINITY	-0.000356		0. *
	IMG:	THETHT	•		

 (\cdot)

table 6: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glas	s sort		
					•		
10			0)0				
		500	1.5				
	> OBJ:	INFINITY	0.000000				
	501:	INFINITY	34.000000				
	SO2:	340.25194	18.000000		'CAF2HL'		
	SO3:	-23456.66512	91.000000				
15	504:	INFINITY	427.039664				
	50 5:	INFINITY	0.000000	٠.			
	506:	339.11803	22.000000		'CAFZHL'		
	507:	677.92271	23.000000				
	508:	-270.98695	13.000000		'CAFZHL'		
٥-	SO9:	-16554.24766	44.216394				
	510:	-179.26036	14.000000		'CAF2HL'		
	511:	-499.04921	16.743922				
	512:	INFINITY	0.000010	REFL			
	5 13 :	244.48659	16.743922	REFL			
	ASP						
25		. 0.000000					
		: YES	CUF: 0.000000 B :- 251110E-13	c :-	130822E-17	מ	680466E-22
		:837113E-10	B :251110E-13 F :646050E-31		0.0000008+00	н	:0.000000E+00
	E	:129779E-26	F :=.646050E-31	9 .	0.000000100	••	
	J	.0.000000.00					
30	514:	499.04921	14.000000		'CAF2HL'		
	\$15:	179.26036	44.216394				-
	516:	16554,24766	13.000000		'CAF2HL'		
	517:	270.98695	23.000000				
		-677,92271	22.000000		'CAF2HL'		
	518: 519:	-339.11803	0.000000				
35	520: 521:	INFINITY	424.039664				
	521:	INFINITY	48.414185				
	522:	INFINITY	60000000				
	523:	INFINITY	0.000000				
	524:	709.73646	35.000000		CAF2HL'		
40	5 25:	-405.70150	1.000000		'CAF2HL'		
	526:	232.80755	20.000000		CAR 2HL		
	527:	383.54136	54.440692 20.000000		'CAF2HL'		
	528:	-399.49382.	1.000000		CAE ARL		
	529:	-455.76820 -581.98648	32.000000		'CAF2HL'		
	530: 531:	-449.85046					
45	211:	-447.03040	13.730273				

table 6: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass sort		
	\$32: \$33:	834.67326 ·504.57916	35.000041 338.825443	'CAF2HL'		
10	ASP:	0.000000				
	IC:	YES	COF: 0.000000	C :123108E-17	D :0.115629E-20	
	A :0	.201937E-07	B :0.255796E-12	G :0.000000E+00		
	E :-	.110440E-24 .000000E+00	F :0.456621E-29	-	+	
15		295.96006	14.999813	'CAF2HL'		
	53å: 535:	178.17958	32,488787			
	536:	304.23731	32.000000	'CAF2HL'		
	537:	-637.25902	81.513603		100 100 .	
	STO:	INFINITY	-10.161100		100 100 100 100	
	538:	160.25766	19.621815	'CAF2HL'	100 100 100 100	
20	539:	250.37700	43.823508		100 , 200	
25	AC : E :0 EC :	0.000000 YES .192340E-07 100 .523462E-25 100 .00000E+00	KC: 100 CUF: 0.000000 B:348224E-12 BC: 100 F:0.264881E-29 FC: 100	CCF: 100 C:223569E-16 CC: 100 G:0.000000E+00 GC: 100	D:380011E-21 DC: 100 H:0.000000E+00 HC: 100	
					100 100	
	541:	369.18529	21.000000	'CAF2HL'	100 100	
30	542:	-739.90155	1.000000			
	543:	137.71809	39.719231	'CAF2HL'		
	544:	762.01416	15.339626			
	545:	-233.76287	10.000000	'CAF2HL'		
	S46:	-1034.38004	1.000000			
35	5 47:	151.43369	35.374148	'CAF2HL'		
55	5 48:	-21273.43749		'CAF2HL'		
	549:	127.02508		CHI ama		
	5 50:	~4741.44116	12.070337			
	ASP K	0.000000		•		
	ic		CUF: 0.00000	00		
40		:0.948304E-07		LO C :281077E-		
		:778064E-19			00+3000000E+00	
	Ĩ	:0.000000E+00		•		
	TMC:	TMFTNTTPS	-0.000337			

:-.278267E-20 :0.000000E+00

table 7: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glas	s sort	
10			. •			
	> OBJ:	INFINITY	0.00000			٠.
	601:	INFINITY	34.000000			
	602.	301.23036	18.000000		'CAF2HL'	
	6 0 3:	9024.85717	91.000000			
	ASP:					
15	K:					
	IC :	YES	CUF: 0.000000	_	15	_
		779174E-08	B :0.228326E-12	C	:0.662071E-17	D
		0.321230E-24	F :133467E-28	G	:0.000000E+00	H
	J :	0.000000E+00				
≥0	604:	INFINITY	372.485723			
	6 €0.5:	INFINITY	0.000000			
	606:	329.24390	22.000000		'CAF2HL'	
	607:	710.76999	19.293465			
	608:	-293.87906	13.000000		'CAF2HL'	
	<u>و</u> و	-968.05522	32.145450			
25	6 10 :	-127.26575	14.000000		'CAF2HL'	
	611:	-404.63828	12.941473			
	612:	INFINITY	0.000010	REFL		
	613:	219.31121	12.941473	REFL		
	6 14:	404.63828	14.000000		'CAF2HL'	
	615:	127.26575	-32.145450			
30	616:	968.05522	13.000000		CAF2HL	
	617:	293.87906	19.293465			
	618:	-710.76999	22.000000		'CAF2HL'	
	619:	-329.24390	0.000000			
	620:	INFINITY	369.485723			
35	621:	INFINITY	95.013130			
	6 22 :	INFINITY	60.000000			
	6 23:	INFINITY	-0.037541 _		'CAF2HL'	
	624:	1056.88268	35.000000		CAPZHU	
	625:	-406.34822	175.000000		'CAF2HL'	
	6 26:	-271.71671	20.000,000		CALZIII	
40	627:	-344.24640	1.000000		'CAF2HL'	
	628:	766.12486	32.000000 10.220682		CMFAHH	
	629:	-1402.78472			'CAF2HL'	
	: 30	385.79357	35.000041		CAP ARM	
	⊊ 31:	559.31200	341.919072			
		-				

table 7: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass sort	
			•		
10	R : 0	0.000000 YES 0.430988E-08 0.362692E-26	CUF: 0.000000 B:0.579328E-14 F:705924E-31	C :0.860442E-18 G :0.000000E+00	D :644328E-22 H :0.000000E+00
15	632: 633: 634:	232.53878 151.97593 240.71208	14_999813· 32.488787 32_000000	'CAF2HL'	
20	635: STO: 636: 637:	2495.46807 INFINITY 153.92754 131.56320	115.579649 -10.161100 19.621815 5.507542	'CAF2HL'	100 100 100 100 100 100 100 100
25	AC : E :- EC :	0.000000 YES 0.298130E-07 100 519344E-24 100 0.000000E+00	KC: 100 CUF: 0.000000 B:0.555237E-12 BC: 100 F:0.690328E-23 FC: 100	CCF: 100 C :0.829224E-17 CC: 100 G :0.000000E+00 GC: 100	D:0.102908E-20 DC:100 H:0.000000E+00 HC:100
30	639: 6 40:	132.44534 1119.94416	30.378652 20.794473	'CAF2HL'	100 100
	6 41: 6 42: 6 43: 6 44:	120.32786 -709.67342 -214.74768 3292.43700	33.748154 11.965434 7.500000 1.000000	'CAF2HL'	
35	645: 646: 647: 648:	108.37386 453.20106 118.78841 -564.84518	35.374148 1.000000 - 36:324916 12.070427	'CAF2HL'	
40	K : IC : A : E :	0.000000	CUF: 0.000000 B:249999E-10 F:0.406332E-22	C :634108E-13	
	TMG ·	THETHTTY	-0.080427		

Thickness RMD

Glass sort

PIK PIK

PIK

PIK PIK

100 PIK

100 100

100

100 100

ō

ō

PIK

HMY 100 100

100

table 8: wavelength = 157,13 nm

Radius

2918.43592

230.27740

-668.85257 · -372.37592

INFINITY

INFINITY

INFINITY

INFINITY

INFINITY

434.25844

Object

716:

717: 718:

119:

720: 721: 722: 723: 724:

725: 726:

10

15

(70

25

30

55

,		THOMASON THE . GIGGO SOIL			
	•	· ·			
		,			
		••			
	Radius	Thickness RMD Glass sort			GLC
> OB.7:	INFINITY	0.000000	100	100	
301:	THEINITY	34.000000	100	100	
₹ 0 2.	276.26597	35.000000 'CAP2HL'	0	100	
103:	1021.75438	95.000000 .	0	100	
ASP					
	0.000000	KC : 100			
	YES	CUF: 0.000000 CCF: 100			
A	:148017E-07	B :0.447070E-12 C :0.503629E-18	D :	232159E	-20
AC.	0	BC : 0 CC : 0	DC :	0	
E	:0.232819E-24	F :764889E-29 G :0.000000E+00		300000E	+00
EC	: 0	FC : 0 GC : 100	HC :	100	
J	:0.000000E+00	1 7			
ac	: 100				
704:	INFINITY	423.855836 -	1.00	0	
705	INFINITY	0.000000	100	100	
70.	372.37592	22.000000 'CAF2HL'	0	100	
70 7:	668.85257	37.501319	0	0	
703:	-230.27740	. 13.000000 'CAF2HL'	0	100	
70%	-2918.43592	38.093680	a	0	
710:	-184.07315	14.000000 'CAF2HL'	0	100	
411:	-413.16131	19.545452	0	0	
712:	INFINITY	0.000010 REFL	100	100	
113:	248.15084	19.545452 REFL	a	PIK	
£14:	413.16131	14.000000 'CAF2HL'	SIK	BIK	-
711	184.07315	38.093680	PIK	PIK	
716:	2918.43592	13.000000 'CAF2HL'	PIK	PIK	

38.093680 13.000000 37.501319 22.000000

0.000000 405.855836

10.680479

27.000000

0.000000

35.000000

175.000000

'CAF2HL'

'CAF2HL'

Thickness RMD

table 8: wavelength = 157,13 nm

5	Object Radius	Thickness H	MD Glass son	
		20.000000	'CAFZHL'	0 100
10 -	ASP: : K: 0.000000 TC: YES A: :0.114541E-07 AC: 0 E::0.683757E-25 EC: 0 J::0.0000008+00	CUF: 0.000000 8:0.514029E-12 BC: 0	CCF: 100 C:658251E-17 CC: 0 G:0.0000002+00 GC: 100	D:0.192605E-20 DC: 0 H:0.000000E+00 HC: 100
15	JC : 100			
	728: -245.97649 729: 461.23130 ASP: K: 0.000000 IC: YES	KC: 100	CAF2HL' CCF: 100 C :0.186983E-16	0 100 0 0
20	A :101414E-07 AC : 0 E :0.216455E-25 EC : 0 .J :0.000000E+00 .JC : 100	BC: 0 F:0.000000E+00 FC: 100	cc : 0	DC: 0 H:0-000000E+00
25	-30: 4028.48297	10.220682 35.000041	'CAP2HL'	0 100 0 · 100
	732: 1133.21363	323.039430		. 100
30	R: 0.00000 IC: YES A: 0.573083E-08 AC: 0 E:506831E-25 EC: 0 J:0.000000E+00 JC: 100	rc: u	CCF: 100 C :0.72232E-17 CC: 0 :0.00000E+00 GC: 100	D: 0.630701E-22 DC: 0 H:0.000000E+00 HC: 100
<i>35</i>	733: 195.44558 734: 143.55672 735: 263.40415 736: -1526.30319 737: 167.78607 738: 403.43077	24.205075. 39.902984 3.439634 29.120237 13.299521	'CAF2HL'	0 100 0 0 0 0 0 0
40	к : 0.000000	KC: 100- CUF: 0.000000 B:256444E-12 BC: 0	CCF: 100 C :0.855972E-17 CC: 0	D:404743E-20 DC: 0
45	E:0.309335E-24 EC:0 J:0.000000E+00 JC:100	FC: 0	G : 0.000000E+00 GC : 100	
	740: INFINITY 740: -259.64850 741: -231.31750	29.339697 30.669679 1.374343	'CAF2HL'	100 0 0 0 0 0
50	K : 0.00000 IC : YES A :0.247745E-0	CUF: 0.000000 B:143625E-11 BC: 0.000000E+00 FC: 100	CC : 0 .000000B+00	D:103761E-19 DC: 0 H:0.000000E+00 HC: 100

table 8: wavelength = 157,13 nm

Object	Radius	Thickness RMD Gla	iss sort

		•			
742:	365.96245	51.763916	'CAF2HL'	٥	o
AC E EC	0.000000 YES 1233481E-08 0 10.190478E-24 10.000000E+00	KC: 100 CUF: 0.000000 8:114992E-11 8C: 0 F:0.000000E+00 FC: 100	CCF; 100 C:0.787872E-16 CC: 0 G:0.000000E+00 GC: 100	DC :	817596E-20 0 000000E+00 100
743: 744: 745:	-578.98949 134.74918 163.80998	1.500000 36.384686 0.500000	'CAF2HL'	0 0	100 0 100
IC A AC E	: 0.000000 : YES :322326E-07 : 0 :0.552969E-25 : 0 :0.000000E+00	KC: 100 CUF: 0.000000 B:0.8193288-11 BC: 0 F:0.000000E+00 FC: 100	CCF: 100 C:0.316811E-15 CC: 0 G:0.000000E+00 GC: 100	DC:	370077E-19 0 000000E+00 100
746: 747: 748: 749:	105.20708 2493.20162 357.29743 ~759.96556 P:	35.374148 1.000000 36.324916 12.069863	'CAF2HL'	0 0 0	100 100 100 PTM

A E E	C: 0 :780604E-21 :C: 0	KC: 700 CUF: 0,000000 8 (0.1139300E-10 BC: 0 F:196532E-24 FC: 0	CCF: 100 C :141125E-13 CC: 0 G :0.000000E+00 GC: 100	0 :0.677942E-17 DC : 0 H :0.000000E+00 HC : 100
		0.000137		100 0

table 9: wavelength = 157,13 nm

10

30

Object	Radius	HIRCKHESS LINA	D 01005 3011	
			: '	
				CCY THC GLC
	INFINITY	0.000000		100 100
08J: 8⊝1:	INFINITY	34.000000		100 100
OI:	251.38730	38.497396	'CAF2HL'	0 0
202: 203: :	603.00415	90.000000		0 100
ASP:	403.00425			
к :	0.00000	KC: 100		
ie :	YES	CUF: 0.000000	CCF: 100	
	.124195E-07	B :-,201050E-12	C :0.136116E-17	D :369989E-21
AC :	G	BC: 0	cc: 0 ·	00: 0
E :0	.571614E-25	F :300137E-29	G :0.000000E+00	H :0.000000E+00
EC :	0 .	FC: 0	GC: 100	HC t IUU.
	.00000000+00			• •
C:	100			
_		460.459734	•	100 0
80 4:	INFINITY INFINITY	0.000000		100 100
2 ⊙ 5 :	-258.59640	22 000000	'CAF2HL'	0 100
\$0 5: \$0 7:	-515.99269	26.483445		o o
20/: 201:	-403.63140	13.000000	'CAF2HL'	0 100
201:	-928.08447	37.951900		0 0
810:	-173.01949	14.000000	'CAF2HL'	0 100
811:	-289,04453	3.607524		ō o
ASP:		•		
к:	0.000000	KC: 100	CCF: 100	
IC:	YES	CUF: 0.00000		D :148322E-21
Α ;-		B :0.442003E-13	C :0.181557E-17	DC: 0
AC :	٥	BC: 0 .	,cc :	52 .
	INFINITY	0.000010 RE	FT.	100 100
&12:	267.30150		FL	O BTK
ξ 13: ASP:	257.30130		•	
K :	0.000000	KC 100 1		
IC:	YES	CUF: 0.00000	CCF: 100	D :843005E-23
λ :	214071E-08	B :0.147481E-13	C :0.128674E-17	
AC :	0	BC: 0 .	cc : 0	DC: 0
				PIK PIK
814:	289.04453	14.000000	'CAF2HL'	FIR FIR
ASP:				

table 9: wavelength = 157,13 nm

5	Object	Radius	Thickness RMD	Glass sort			
	. K : IC : A :0		.0	CCF: 100 C:181557E-17	D :0.14	18322E-21	
10	yc :			CC: BIK	DC:	PIK	
	215:	173.01949	37.951900			PIK	
	816:	928.08447	13.000000	'CAF2HL'		PIK PIK	
	217:	403.63140	26.483445	'CAF2HL'		PIK	
	2 18:	515.99269	22.000000	CAPZHL		PIK	
15	3 19:	258.59640	0.000000 .447.459734 .			PIK	
	2 20:	INFINITY INFINITY	60.000000			100	
	\$21: \$22:	INFINITY	15.356414			HMY	
	2 22:	INFINITY	40.000000			100	
	824:	INFINITY	0.000000			100	
	825:	633.39437	35.000000	'CAF2HL'	0	700	
\$0	826:	-347.37162	119.686124			100	
-	& 27:	-211.26446	20.000000	'CAF2HL'	ă	100	
	§ 28:	-237.58727	1.055156	'CAF2HL'	ă	ā.	
	2 29:	550.08434	40.000000 40.249917	CAPTILD	ō	٥	
	8 30:	-612.80061 -201.71052	35.000000	'CAF2HL'	à	100	
25	231: 232:	-322.70560	321.354243		0	٥	
	232: 233:	-585.62058	9.084229	'CAF2HL'	0	0	
	₹34:	367.59560	18.890606	-	0	a	
	ASP:						
	к :		KC: 100	CCF: 100			
	IC :	YES	CUF: 0.000000 B :169007E-12	CCF: 100 C:334287E-17	D :0.4	4204321-2	1
30		0.290547E-07	BC :1890078-12	CC : 0	DC :	٥	
	AC :		ac : u		•		
	&35:	1157,44840	32.000000	'CAF2HL'		.100	
	236:	-274.28444	43.654547		0	0	
	836: 837:	189.47888	45.000000	CAFZHL'	0	0	
35	838:	724.11587	12.838681		100	ö	
00	.97 0:	INFINITY	29.998948	CAF2HL'	200	ŏ	
	840:	299.02718	33.232875	CAF 2HL	ō	ō	
	2841:	1469.50622	12.574830 31.660134 .	.CAF2HL.	0	0	
	242:	161,10860 1679,93121	12.291388		٥	٥	
/ -	. 843:	-1595.69234	: 44.999319	- CAP2HL	۵	0	
40	ASP						
	ĸ ·		KC: 100				
	IC	: YES	CUF: 0.000000		6 D 1-	.176968E-	20
		831600E-07	B :0.176877E-12.	CC: 0	DC:	a	
	AC	; 0	•	44 .			
45	845:	-574.39812	1.000000			100	100
45	846:	105.0128	35.374148			100	100
	847:	447.3832	1.000000			100	100
	848:	518.2801	5 36.324916	'CAF2HL'		100	100
-		•					
	849:	-590.37066	12.070070		٥	PIM	
50	ASE						
	K	. 0.00000	KC: 100				
	IC		CUF: 0.000000	CCF: 100 C :0.111640E-1	1 0	.285686E	-17
	Ä		B :225496E-10	CC: 0.111840E-1	DC:	0	
	AC	:- 0	BC: 0				
	=	INFINITY	-0.000069	•	100	٥	
55	. IMG:	THE THT A.		•			-

table 10: wavelength = 157,63 nm

Object	Radius	Thickness RMD	(Glass sort		
Reference	Raclius	Thickness	•	Glass		
number	RDY	THI R	200	OLA.		
087	INFINITY	34.000000				
1:	INFINITY	4.000000				
1002:	312.33717	18.000000		CYLS,		
A0D3:	9682.90099	83.008000				
40041	INFINITY	R 000000.0	EFL.			
XDE:		YDE: 0.000000	208:		Ben	
ADE	52,000000	BDE: 0.000000	COE	0.00000		
5 :	INFINITY	-414.787259		'CLF2'		
·100 6 r	-405.55295	-22.000000		CLEA		
1007:	-2462.67101	-41.116913 -13.000000		'CAFA'		
400 a	203.79683	-33.321295		· unes		
4009:	1426.67172	-14.00Q000		'CAP2'		
-(01:0:	176.13502 480.49454	-16.561783		CID 4		
4011: -0012:	241.21296		RPL			
13:	480.49454	14.000000		'CAF2'		
14:	176.13502	33,321295				
15:	1424.67172	13.000000		'CAP2'		
15:	203.79683	41.716913				
17:	-2462,67101	22.000000 .		'CAFA'		
LB:	-405.55295	409.787259				
1.9 1	INFINITY	0.000000				
AD 201	INFINITY	-70.541305 1	REPL			
XDE	2000000.0	0.000000	ZDE:		BES	ı
ADE		BDE: 0.000000	CDE:	0.00000		
IMI 21:	Infinity	59.941156				
-{0 22:	-150.01878	-20.602459		CAF2		
asp						
×	, 0.000000	CUP: 0.000000				
	YES	B :0.103665E-13	c :	0.352915E-16	D	:-1.7849518-21.
Ž.	:0.141974E-07 :0.116720E-24	P :256130E-29	č	0.000000R+00	B	:0.0000002+00
ã	10.000000000000000000000000000000000000					
•		•				
1023:	-179.90445	-6.322544				
1024:	-210.09796	-39.34.6550		CYLS.		
ASP	1					
x	0.000000					
	: YES	CUP: 4,000000		12C1 DATE 1.C	ם	10.379837E-21
A.	:0.7678258-10	B :0.128720E-13		:336180E-16	н	0.04300000000
15	:119676E-24	F :0.1860238-43	•	0.000000	п	: 0.000002+00
J	:0.0000002+00					
1025:	473.11548	-103.837418				
1026	3696.82552	-15.000000		'CNF3'		
ASI	P 1					
x	: 0.000000					
10	1 YES	CUP: 0.000000	_	:152523E-16	۵	:211663E-22
. А	:0.254112E-07	B :369099E-12 F :220459E-31	G	:0.000000E+00	ĸ	:0.0000000E+00
B	10.3934832-25	F 1220439E-31	G	10,0000005+00	п	;0.0000402000
J	:0.000000E+00					
1027:	-1457.62061	-116.883653				
40 28:	245.07294	-15,478383		'CAF2'		
10 28:	470.01293	-119.415520				
70 49:		1201-120-1				
K.	. 0.000000					
ic		CUT: 0.00000				
A	:0.248698E-08	B :133539E-11	· c	:100200E-16	D	:278441E-21
E	:245690E-25	F :0.118955E-29	G	:0.0000QE+0D	Я	10.00000E+00
J	:0.0000005+00					-
		10 10015		·CAP2		-
1030:	-211.14451	-46.407461		· CAPA·		
10 31:	390.08349	-41.599722 -15.000000		·CAP2 ·		
4032:	214.84948 -152.90981	-22.009325				
10331	-152,9Q981 P:	-24.003323				
. AS	. 0.000000					
	. 4.00000					

table 10: wavelength = 157,63 nm

Radius

Object

10

			-	
			•	
			.,	•
,			V	
		•		
	TC: YES	CUF: 0.000000	•	
		B :0.2271478-11	C :0.653352B-16	D :0.531753E 21
5		F .0.184559B-29	G :0.0000005+00	H :0.000000E+00
	E : .466831E-25	F .U.1242232		
	J :0.0000000+00			
		•		
	10 34: -456.24753	-36.555361	'CAF2'	
	10 35: 231.78386	-1.000000		
	1036: 3335.79137	-13.249069	* t:A#2 *	
o		-1.000000		
		-4.032535		
		-46.695487	'CAF2'	
	6 39: -158.37404	-0.999916		
	10 40: -287.83268		'CAF2'	
	1041: -174.28171	-11.999B77	CAF2	•
	1042: -127.11599	-15.767825		
25	ASP:			
	K : 0.000000			
	IC YES	CUF: 0.000000		
		B :- 218987E 11	C :745527E-16	D 1678130E-20
		P :- 111046E-27	0.00000008+00	H :0.00000E+00
	E :0.949579E-24	F , 1225422 2.	. ,	
	J .0.000000E+00		•	
			CVL3.	
30	4443: -215.90706	-41.405295	· Chra	
	1044: 241.65885	-1.000000		-
	1045: -92.14326	-44,385959	CAF2	
	1046: -251.19562	-2.210034		
	ASP:			
		CUP: 0.000000		•
35		B :301574E-11	C :132486E-14.	D :0.194427E-18
	A :U.901760E-07	F : 272720E-27	G : D.000000E+00	B :0.000000F+00
	E :0,127620E-22	B : 2/2/2014-2/	G :0.00000000000	
	J .0.000000E+00			
			ALC: Your Land	
	4047: -163.12030	-46.650069	CAP2	
	4B: INFINITY	0.00000 .	'CNF2'	
40	4049: 551.37429	0.000000		
	ASP:			•
	K : 0.000000			
	IC: YES	CUF: 0.000000		
		B :14954DE-10	C :0.934774E-15	D :100734E-16
	A :743735E-07	F :- 149893E-23	G :0.000000E+00	H :0.000000E+00
	E :0.533395E-20	F :163833E-23		-
45	J :0.0000000x+00			
	50: INFINITY	-6.000000	, CYL3,	•
	51: INFINITY	-11.999873		
	IMG: INFINITY			
	A			

Claims

- f. Projection exposure lens with
 - 1.1 an object plane
 - 1.2 optical elements for separating beams

- 1.3 a concave mirror
- 1.4 an Image plane
- 1.5 a first lens system arranged between the object plane and the optical elements for separating beams
- 1.6 a second double passed lens system arranged between the optical elements for separating beams and
- 1.7 a third lens system arranged between the optical elements for separating beams and the image plane characterized in that
- 1.8 at least one of the lens or mirror surfaces of the first, second or third lens system is aspheric and the numerical aperture NA of the projection exposure lens is 0,7 or greater, preferably 0,8 or greater with a maximum image height exceeding 10 mm.
- 2. Projection exposure lens according to claim 1, characterized in that the second lens system comprises a maximum of five lenses.
- 3. Projection exposure lens with

5

10

20

- 3.1 an object plane
- 3.2 optical elements for separating beams
- 3.3 a concave mirror
- 3 4 an image plane
 - 3.5 a first lens system arranged between the object plane and the optical elements for separating beams 3.6 a second double pass lens system arragend between the optical elements for separating beams and the
 - 3.7 a third lens system arranged between the optical elements for separating beams and the image plane
 - characterized In that 3.8 the second lens system comprises a maximum of five lenses.
- Projection exposure lens according to claim 1-3, characterized in that
- the second lens system comprises two lenses. 30
 - 5. Projection exposure lens according to claim 1-4, characterized in that the second lens system comprises three lenses.
 - 6. Projection exposure lens according to claim 1-5, characterized in that the two lenses are negative lenses.
- 7. Projection exposure lens according to claim 1-6, 40 characterized in that the at least two lenses of the three lenses are negative lenses.

 - 8. Projection exposure lens according to claim 4, characterized in that
 - the distance between the vertices of the two lenses of the second lens system is smaller than 0,6 *diameter, preferably 0,5*diameter of the concave mirror.
 - 9. Projection exposure lens according to claim 5,
- characterized in that the three lenses consist of a first, a second and a third lens and that the distance between the vertices of the first and the third lens of the second lens system is smaller than 0,6 *diameter, preferably 0,5 diameter of the concave
- 10. Projection exposure lens according to claim 4, characterized in that the diameter of each of the two lenses is greater than 1.1" diameter, preferably 1,2" diameter of the aperture stop.

- 11. Projection exposure lens according to claim 5, characterized in that
 - the diameter of each of the three lenses is greater than 1.1" diameter, preferably 1,2" diameter of the aperture stop.
- 12. Projection exposure lens according to claim 4,

characterized in that

the distance between the optical elements for separating beams and the first of the two lenses of the second lens system is greater than 1,5° preferably 1,8° diameter of said lens.

13. Projection exposure lens according to claim 5,

characterized in that

the distance between the optical elements for separating beams and the first of the three lenses of the second lens system is greater than 1,5° preferably 1,8°diameter of said lens.

14. Projection exposure lens according to claim 1-13,

characterized in that

the optical elements for separating beams are comprising a beam splitter or a folding surface.

15. Projection exposure lens according to claim 1-14,

characterized in that

25

30

45

50

55

rms wavefront aberration is less than 20 milliwaves, preferably less than 10 milliwaves.

16. Projection exposure lens according to the claim 1-15, characterized in that the first lens system consists of one lens.

- Projection exposure lens according to claim 16.
- characterized in that the one lens of the first lens system is a positive lens.
- 18. Projection exposure lens according to claim 16-17, characterized in that the one lens of the first lens system has at least one aspheric surface.
 - 19. Projection exposure lens according to claim 14-18, characterized in that the surfaces for folding a beam are comprising two folding mirrors.
- 20. Projection exposure lens according to claim 19, characterized in that the folding mirrors are internal surfaces of a prism.
 - 21. Projection exposure lens according to claim 20,
 - characterized in that the prism material has an refractive index greater than 1, 4.
 - 22. Projection exposure lens according to claim 21, characterized in that the prism material has an expansion coefficient smaller than 10-6K-1 in the temperature region -20° C to +300° C.
 - 23. Projection exposure lens according to claim 19-22, characterized in that the surface of the folding mirrors are coated with reflection enhancing thin films.
 - 24. Projection exposure lens according to claim 19-23, characterized in that the folding mirrors comprise at least one aspheric surface.
 - 25. Projection exposure lens according to claim 1-24, characterized in that the second lens system and the concave mirror are arranged along an unfolded optical axis.
 - 26. Projection exposure lens according to claim 25, characterized in that the folding mirrors are arranged in the region where the optical axis of the first lens system and the second lens system crosses.
 - 27. Projection exposure lens according to claim 19-26,

characterized in that the folding angle deviates from 90° such that at the lenses of the second double passed lens system and the concave mirror are more distant from the object plane than the first lens of the first lens system is.

- 28. Projection exposure lens according to claim 1-28, characterized in that
 - the projection exposure lens comprises an intermediate image.
- 29. Projection exposure lens according to claim 28, characterized in that
 - the intermediate image is situated in the third lens system.
- 30. Projection exposure lens according to claim 28,
- characterized in that the intermediate image is situated between the optical elements for separating the beams and the first lens of the third iens system.
 - 31. Projection exposure lens according to claim 1-30, characterized in that the third lens system comprises the aperture stop.
- 32. Projection exposure lens according to claim 31, 20 characterized in that the third lens system comprises a long drift space without lenses located between the intermediate image and the aperture stop.
 - 33. Projection exposure lens according to claim 31,
 - characterized in that the drift section between the intermediate image and the aperture stop without lenses is greater than 25 % of the distance between the optical elements for separating beams and the image plane.
 - 34. Projection exposure lens according to claim 28-33, characterized in that
- within 50% of the distance between the intermediate image and the image plane beginning with the intermediate 30 image in the third lens system at maximum 4 lenses are located.
 - 35. Projection exposure lens according to claim 32-34, characterized in that the lenses of the third lens system are density packed between the aperture stop and the image plane.
 - 36. Projection exposure lens according to claim 28-35,

35

40

45

- characterized in that the plane of the intermediate image is freely accessible.
- 37. Projection exposure lens according to claim 36, characterized in that in the plane of the intermediate image a field stop is located.
 - 38. Projection exposure lens according to claim 1-37, characterized in that the subsystem composed of the second lens system and the concave mirror comprises an aspheric surface.
 - 39. Projection exposure lens according to claim 38, characterized in that the lens of the second lens system next to the concave mirror comprises an asphenc surface.
- 40. Projection exposure lens according to claim 38-39, characterized in that the concave mirror comprises an aspheric surface. 50
 - 41. Projection exposure lens according to claim 39-40, characterized in that the lens next to the concave mirror comprises an aspheric surface, which is situated opposite to the surface of the concave mirror.
 - 42. Projection exposure device, according to claim 41, characterized in that the concave mirror comprises an aspheric surface.

- 43. Projection exposure lens according to claim 38-42, characterized in that a aperture stop is situated in the third lens system and the condition h/\$ >1.2 for one or more of the aspheric surfaces is fulfilled, where h is the height at each lens surface of the light beam that is assumed to be emitted from the intersection of the optical axis of the object plane and passes through the lens surface with the maximum numerical aperture and \$\phi\$ is the radius of the diaphragm of the aperture in the third lens group.
- 44. Projection exposure lens according to claim 1-43, characterized in that at least one surface of the lenses of the third lens system is aspheric.
- 45. Projection exposure lens according to claim 44, characterized in that at least one aspheric surfaces of the lenses of the third lens system is located before the aperture plane and at least one behind the aperture plane.
 - 46. Projection exposure lens according to claim 44-45, characterized in that one of the surface of the lens next to the image plane is aspheric.
 - Projection exposure lens according to claim 1-46, characterized in that all lenses of the projection exposure lens are made of the same material.
 - 48. Projection exposure lens according to claim 1-47, characterized in that the lenses are made of a first material and of a second material, wherein no more than four, preferably no more than three lenses are made of said second material.
 - 49. Projection exposure lens according to one of the claims 47 or 48, characterized in that the first material and/or second material is quartz glass and/or LIF and/or CaF₂ and/or BaF₂ or another fluoride crystal.
 - 50. Projection exposure lens according to claim 49 characterized in that depending from the wave length of light travelling through the projection exposure lens the following material is used: 180 < λ < 250 nm: quartz and/or CaF₂</p>
 - 120 < λ < 180 nm: CaF₂ and/or BaF₂

5

30

35

55

- Projection exposure lens according to claim 1-50, characterized in that the third lens system is composed of a field lens group, an intermediate correcting lens group and a focusing lens group.
 - Projection exposure lens according to claim 51, characterized in that the third lens system comprises

said field lens group is of positive refractive power said intermediate correcting lens group is of positive or negative refractive power said focussing lens group is of positive refractive power.

- 45 53. Projection exposure lens according to claim 1-52, characterized in that at least one "-power doublet with a negative power lens and a positive power lens in this sequence from the object side is arranged in sald third lens system.
 - 54. Projection exposure lens according to claim 1-53, characterized in that the projection exposure system comprises a intermediate image and the imaging ratio between the object plane and the intermediate image plane is greater than 0.90, but different from unity.
 - 55. Projection exposure lens according to claim 1-54, characterized in that the projection exposure system comprises a intermediate image and the third lens system comprises at least a pair of menisci, the convex surface of the intermediate-image-side meniscus facing to the intermediate image, the convex surface of the other facing oppositely.
 - 56. Projection exposure lens according to claim 51-55, characterized in that said at least one pair of meniscl is arranged

in said Intermediate correcting lens group.

- Projection exposure lens according to claim 51-55, characterized in a -+power doublet is arranged in said focussing lens group.
- 58. Projection exposure lens according to claim 53-57, characterized in that one of said →power doublets is arranged next to the aperture plane in the third lens group.
- Projection exposure lens according to claims 1-58, characterized in that the longitudinal chromatic aberration is less than 0.015 µm per a band width of 1 pm at 193 nm.
 - Projection exposure lens according to claim 1-59, characterized in that the longitudinal chromatic aberration is less than 0.05

 µm per band width of 1 pm at 157 nm.
- 61. Projection exposure lens according to claim 1-60, characterized in that it is both side telecentric.
 - 62. Projection exposure apparatus comprising
 - an UV-laser light source

10

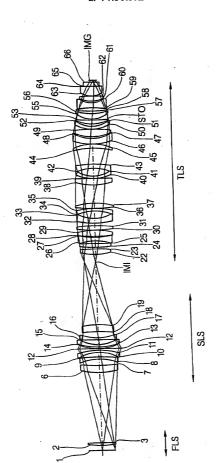
20

35

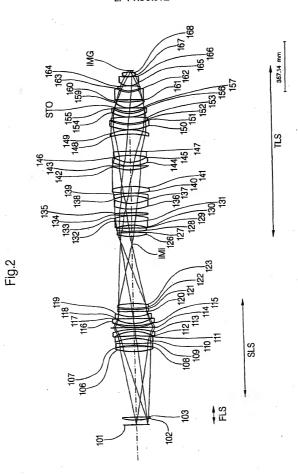
50

- an illuminating system
- a mask handling and positioning system
 - a projection exposure lens according to at least one of claims 1 to 61
 - a wafer handling and positioning system.
- 25 63. A method of producing microstructured devices by lithography making use of a projection exposure apparatus according to claim 62.
 - 64. A method according to claim 63, characterized in that use is made of step- and repeat, scanning or stitching exposure schemes.

342.47 mm

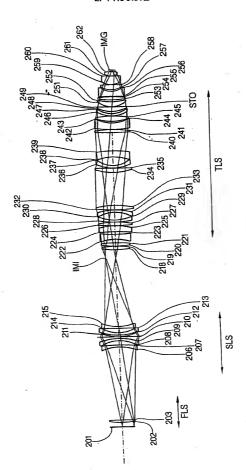


. .



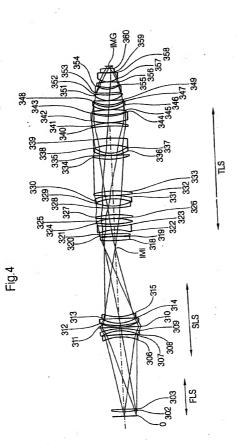
 $(\hat{x}_{i,j},\hat{x}_{i,j})$

36

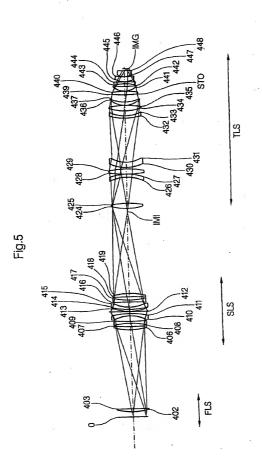


C

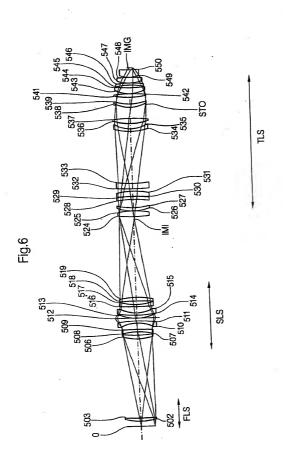
347.22 mm



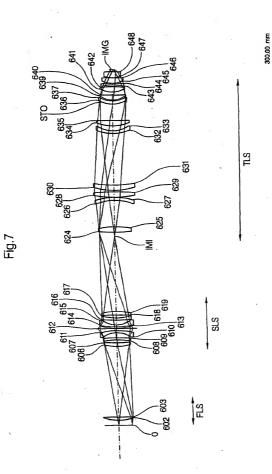
(;



300.00 mm

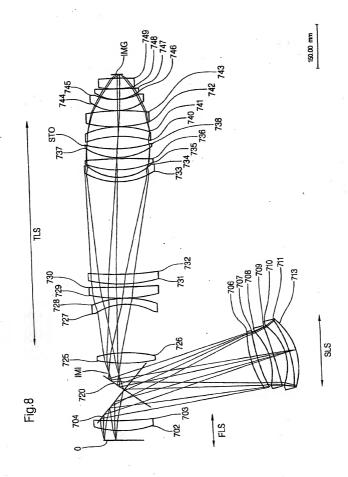


(:



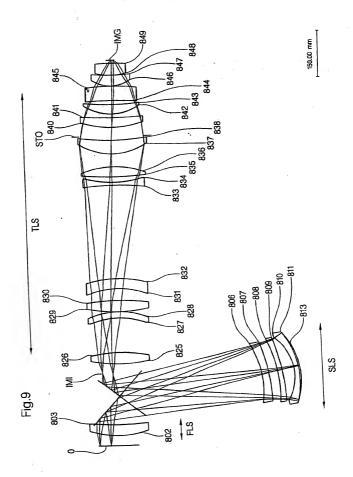
 \bigcirc

()



(:

 ϵ



(]

(†

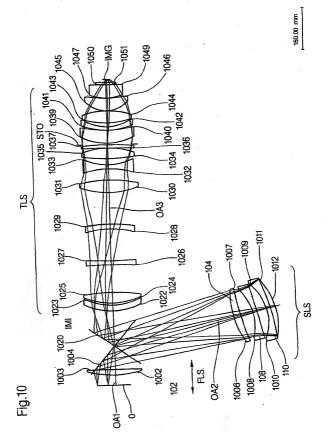


Fig.11

